

Surface Mount Schottky Barrier Rectifier

Reverse Voltage - 20 to 200 V

Forward Current - 8 A

FEATURES

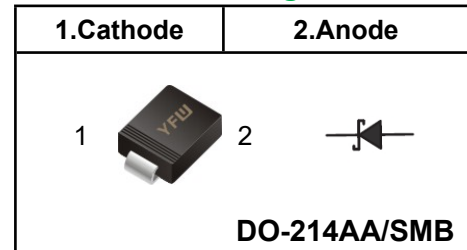
- ◆Metal silicon junction, majority carrier conduction
- ◆For surface mounted applications
- ◆Low power loss, high efficiency
- ◆High forward surge current capability
- ◆For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ◆Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

- ◆Case: DO-214AA/SMB
- ◆Terminals: Solderable per MIL-STD-750, Method 2026
- ◆Approx. Weight: 0.095g / 0.003oz

Absolute Maximum Ratings and Electrical characteristics
 Ratings at 25 ° ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

Pinning



Marking Code

SS82B	SS82
SS84B	SS84
SS86B	SS86
SS88B	SS88
SS810B	SS810
SS812B	SS812
SS815B	SS815
SS820B	SS820

Parameter	Symbols	SS82B	SS84B	SS86B	SS88B	SS810B	SS812B	SS815B	SS820B	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	40	60	80	100	120	150	200	V
Maximum RMS voltage	V_{RMS}	14	28	42	56	70	84	105	140	V
Maximum DC Blocking Voltage	V_{DC}	20	40	60	80	100	120	150	200	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	8.0								A
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed On Rated Load (JEDEC method)	I_{FSM}	170								A
Maximum Instantaneous Forward Voltage at 8 A	V_F	0.55		0.70		0.85		0.90		V
Maximum Instantaneous Reverse Current at Rated DC Reverse Voltage <small>$T_A = 25^{\circ}C$ $T_A = 100^{\circ}C$</small>	I_R	1.0 50				0.3 25				mA
Typical Junction Capacitance ⁽¹⁾	C_j	650				420				pF
Typical Thermal Resistance ⁽²⁾	$R_{\theta JA}$	10								°C/W
Operating Junction Temperature Range	T_j	-55 ~ +150								°C
Storage Temperature Range	T_{stg}	-55 ~ +150								°C

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

Fig.1 Forward Current Derating Curve

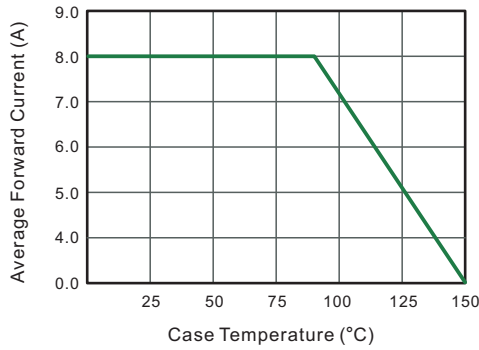


Fig.2 Typical Reverse Characteristics

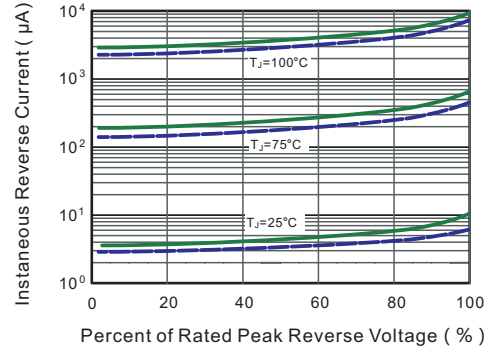


Fig.3 Typical Forward Characteristic

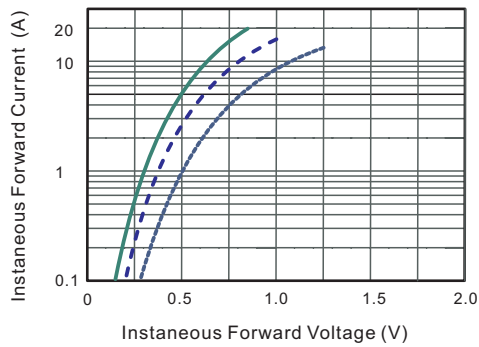


Fig.4 Typical Junction Capacitance

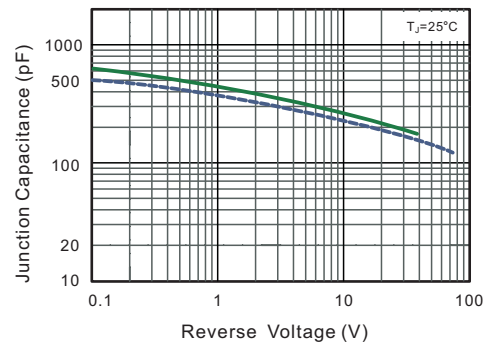


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

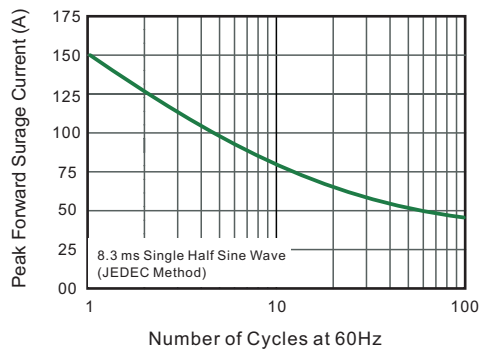
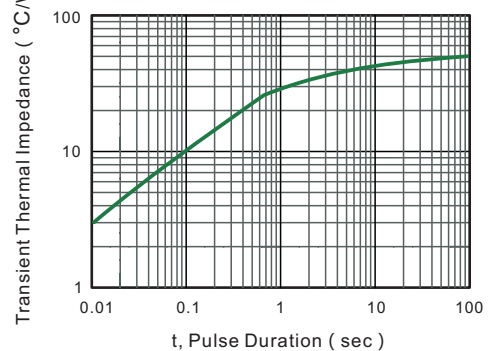
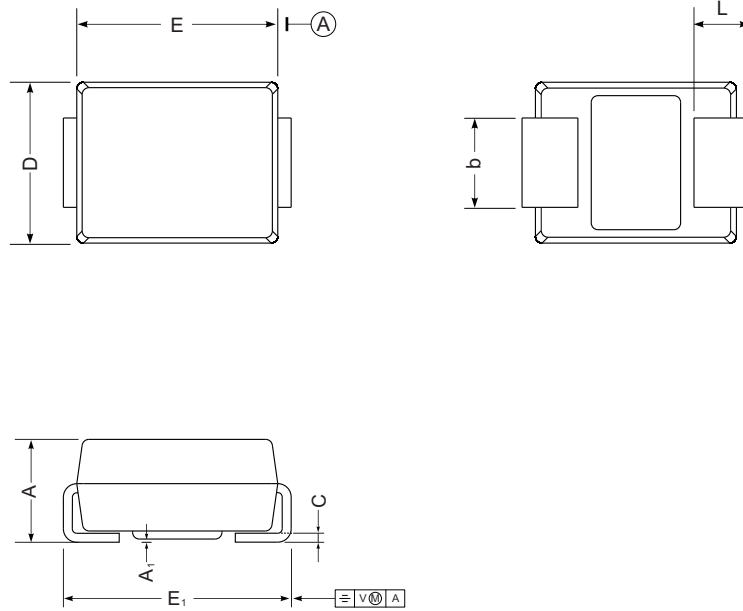


Fig.6- Typical Transient Thermal Impedance



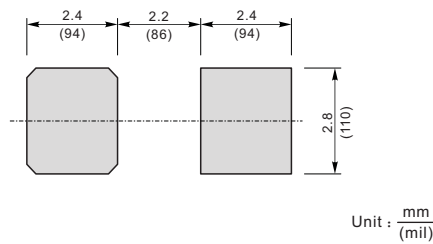
Package Outline DO-214AA SMB

Plastic surface mounted package; 2 leads



UNIT		A	E	D	E ₁	A ₁	L	C	b
mm	max	2.44	4.70	3.94	5.59	0.20	1.5	0.305	2.2
	min	2.13	4.06	3.3	5.08	0.05	0.8	0.152	1.9
mil	max	96	185	155	220	7.9	59	12	87
	min	84	160	130	200	2.0	32	6	75

The recommended mounting pad size



Summary of Packing Options

Package	Packing Description	Packing Quantity	Industry Standard
DO-214AA SMB	Tape/Reel, 13" reel	3000	EIA-481-1

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